

Synergetic Synthesis of Carbon-Carbon & Metal-Carbon Composites of Atomic Scale

Benjamin F. Dorfman, Presentation for Clarkson University. CAMP. 2005

New family of nanostructured ultra-light weight carbon based materials approaching the utmost physical limit of composite solid

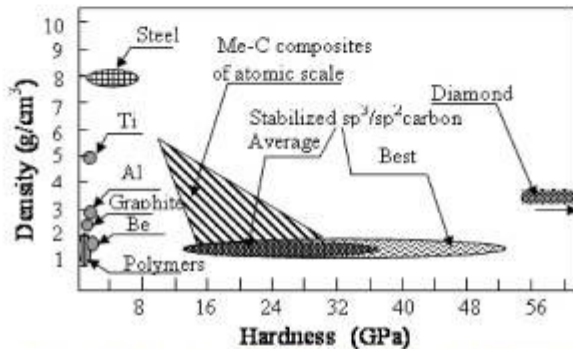


Figure 2: Density vs. Hardness for Stabilized Amorphous Carbon and other materials

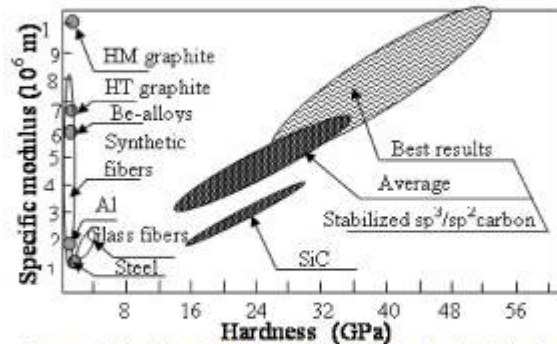
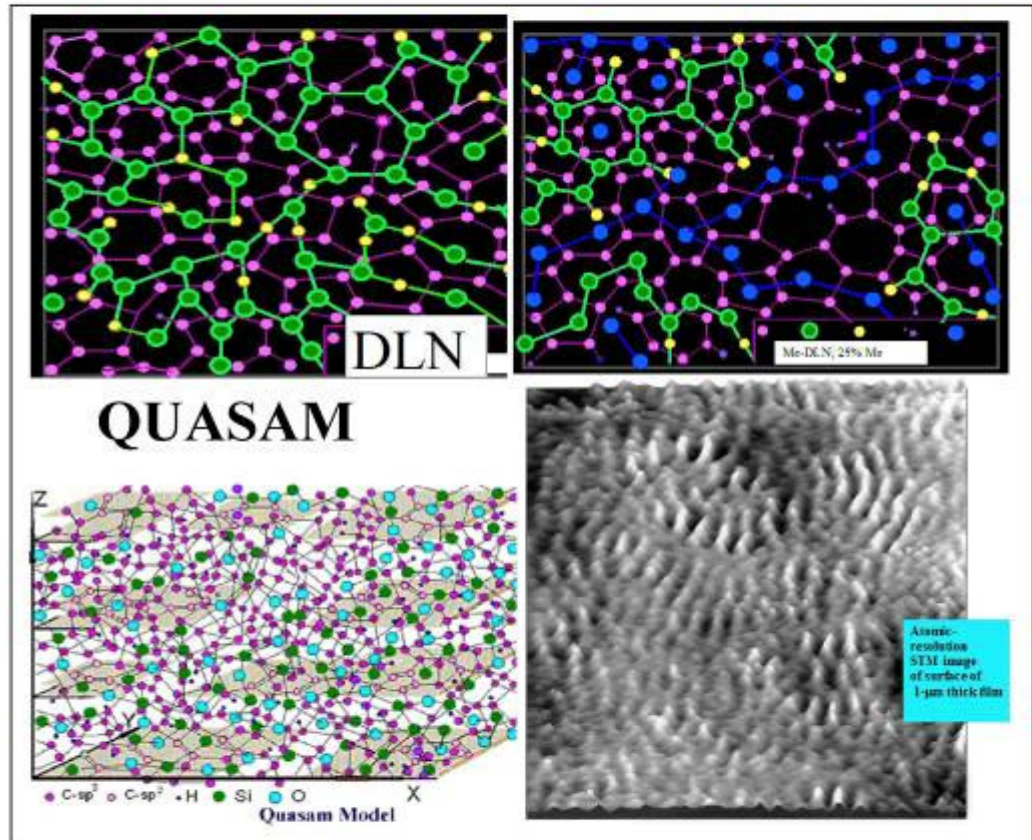


Figure 3: Specific Modulus vs. Hardness for Stabilized Amorphous Carbon and other materials

First in US and in the world patents on Nano-composites (from 1991, now ~20).



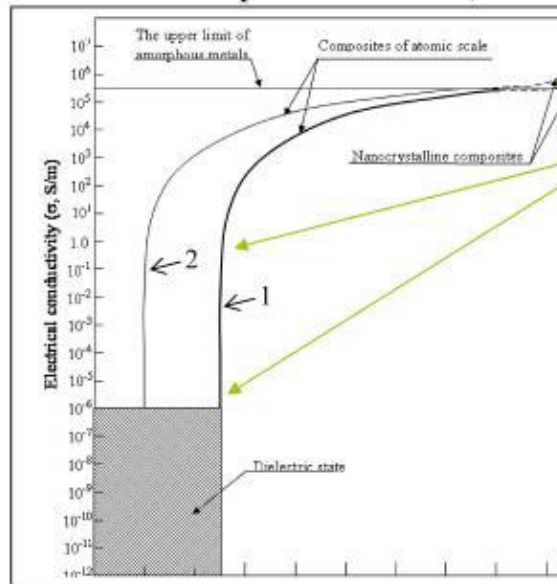
Chemical stabilization shifts the graphite-diamond equilibrium. Silicon-stabilized and silica-stabilized $sp^3: sp^2$ carbon solids are **virtually stress-independent**. long-term thermal stability 400-650°C, short-term thermal stability 550-950°C

NOW: multifunctional coatings: surface reinforcement, best tribology in any humidity & water, anti-icing, electric. tunable, capability for topographic stress monitoring sensors' system
Potentially – smart self-monitoring ultra-light weight construction material

ELECTRONIC PROPERTIES

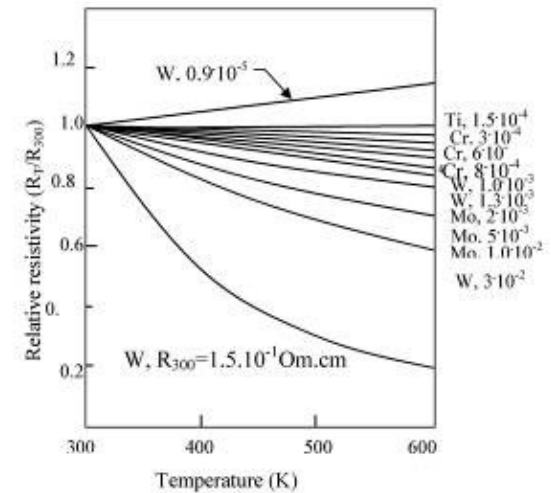
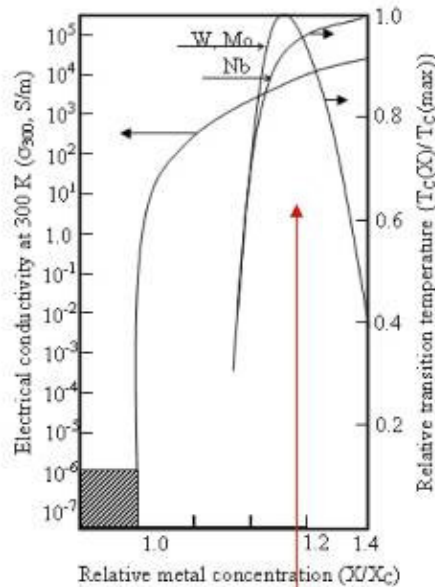
Benjamin F. Dorfman, Science Dr., Clarkson University, CAMP

Atomic-Scale Composites (ASC) represent a new type of solid media allowing controllable variation of all the major electronic transport mechanisms, including low temperature superconductivity with extremely high critical magnetic field.



Electrical Conductivity of diamond-like Me-carbon ASCs versus the volume metal concentration for all examined metals.

- 1 – metals with small atomic radius (such as Ni, Co)
- 2 – metals with large atomic radius (such as Hf, Zr)



Optical properties of ASC may be varied in a relatively broad range as well. Thus, ASC are important electronic, micro-electro-mechanic and photonic materials.

Superconductivity transition temperature (T_c) vs metal concentration (X) near the percolation threshold (X_c). Two kinds of dependencies observed : monotonous (in {Nb|C}) and with maximum ({W|C} and {Mo|C}).

Resistivity of Me-DLN films vs. temperature in the range of 300– 600 K. The room-temperature values of resistivity R_{300} are indicated for each plot. The proper metal-dielectric atomic scale composites possess negative temperature coefficient of resistivity